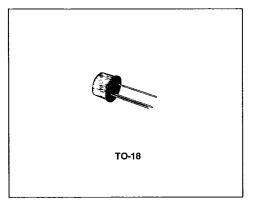
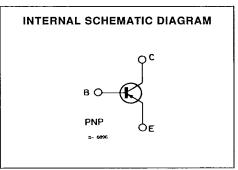
## LOW NOISE GENERAL PURPOSE AUDIO AMPLIFIERS

#### DESCRIPTION

The BC477, BC478 and BC479 are silicon planar epitaxial PNP transistors in TO-18 metal case. The BC477 is a high voltage type designed for use in audio amplifiers or driver stages, and in the signal processing circuits of TV sets. The BC478 and BC479 are respectively low noise and very low noise types, designed for general preamplifier or amplifier applications.





#### **ABSOLUTE MAXIMUM RATINGS**

Cumbal	B		Unit		
Symbol	Parameter	BC477	BC478	BC479	
VCES	Collector-emitter Voltage (V <sub>BE</sub> = 0)	- 90	- 40	- 40	V
VCEO	Collector-emitter Voltage (I <sub>B</sub> = 0)	- 80	- 40	- 40	V
VEBO	Emitter-base Voltage (I <sub>C</sub> = 0)	- 6			V
lc	Collector Current	- 150			mA
Ptot	Total Power Dissipation at $T_{amb} \le 25 \text{ °C}$ at $T_{case} \le 25 \text{ °C}$	0.36 1.2			w w
T <sub>stg</sub>	Storage Temperature	- 55 to 200		°C	
Т,	Junction Temperature	200		°C	

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### THERMAL DATA

R <sub>th J</sub> -case	Thermal Resistance Junction-case	Max	146	°C/W
R <sub>th j-amb</sub>	Thermal Resistance Junction-ambient	Max	485	°C/W

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#### ELECTRICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C unless otherwise specified )

Symbol	Parameter	Test Conditions	Min.	Тур.	Max,	Unit
I <sub>CES</sub>	Collector Cutoff Current (V <sub>BE</sub> = 0)	for BC477 $V_{CE} = -70 V$ $V_{CE} = -70 V$ $T_{amb} = 125 °C$ for BC479-BC478 $V_{CE} = -30 V$ $V_{CE} = -30 V$ $T_{amb} = 125 °C$			- 10 - 10 - 10 - 10	nA μA nA μA
I <sub>EBO</sub>	Emitter-cutoff Current (I <sub>C</sub> = 0)	V <sub>EB</sub> = - 4 V			- 10	nA
V <sub>(BR)CES</sub>	Collector-emitter Breakdown Voltage (V <sub>BE</sub> = 0)	I <sub>C</sub> = - 10 μA for BC477 for BC478 for BC479	90 40 40			V V V
V <sub>(BR)CEO</sub>	Collector-emitter Breakdown Voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = - 5 mA for BC477 for BC478 for BC479	- 80 - 40 - 40			V V V
V <sub>(BR)EBO</sub>	Emitter-base Breakdown Voitage (I <sub>C</sub> = 0)	l <sub>E</sub> = - 10 μA	- 6			V
V <sub>CE(sat)</sub> *	Collector-emitter Saturation Voltage	$I_{C} = -10 \text{ mA}$ $I_{B} = -0.5 \text{ mA}$ $I_{C} = -100 \text{ mA}$ $I_{B} = -5 \text{ mA}$		- 0.1 - 0.3	- 0.25	v v
V <sub>BE</sub> *	Base-emitter Voltage	$I_c = 2 \text{ mA}$ $V_{CE} = -5 \text{ V}$	- 0.55	- 0.65	- 0.75	v
V <sub>BE(sat)</sub> *	Base-emitter Saturation Voltage	$I_{C} = -10 \text{ mA}$ $I_{B} = -0.5 \text{ mA}$ $I_{C} = -100 \text{ mA}$ $I_{B} = -5 \text{ mA}$		0.75	- 0.9	v
h <sub>FE</sub> *	DC Current Gain	$\begin{split} I_{C} =& -10 \; \mu A & V_{CE} =& -5 \; V \\ & for \; BC477 \\ for \; BC478 \\ for \; BC479 \\ I_{C} =& -2 \; mA & V_{CE} =& -5 \; V \\ & for \; BC479 \\ I_{C} =& -10 \; mA & V_{CE} =& -5 \; V \\ & for \; BC478 \\ for \; BC479 \\ I_{C} =& -10 \; mA & V_{CE} =& -5 \; V \\ & for \; BC477 \\ for \; BC477 \\ for \; BC477 \\ for \; BC478 \\ fo$	30 50 100 110 110 200	115 195 290 160 270	250 450	
h <sub>fe</sub>	Small Signal Current Gain	$\label{eq:constraint} \begin{array}{c} & \mbox{for BC479} \\ I_C = -2 \mbox{ mA} \\ f = 1 \mbox{ kHz} \\ for BC477 \\ for BC478 \\ for BC478 \\ for BC479 \\ I_C = -10 \mbox{ mA} \\ f = 20 \mbox{ MHz} \\ \end{array} $	125 125 220	350 7.5	260 500	

\* Pulsed : pulse duration = 300  $\mu s$ , duty cycle = 1 %.

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SGS-THOMSON MICROELECTRONICS

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### S G S-THOMSON

### BC477-BC478-BC479

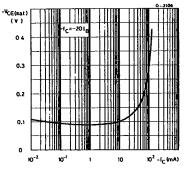
### ELECTRICAL CHARACTERISTICS (continued)

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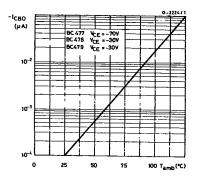
Symbol	Parameter	Test 0	Conditions	Min.	Тур.	Max.	Unit
Ссво	Collector-base Capacitance	l <sub>E</sub> = 0	$V_{CB} = -5 V$		4	6	pF
C <sub>EBO</sub>	Emitter-base Capacitance	I <sub>C</sub> = 0	V <sub>EB</sub> = - 0.5 V		11	15	pF
NF	Noise Figure	$I_{C} = -20\mu A$ $R_{g} = 10k\Omega$ f = 10 Hz to 10 B = 15.7  kHz			0.0	0.5	JD
			for BC479	ļ	0.8	3.5	dB
NF	Noise Figure	$R_g = 2 k\Omega$	f = 10 Hz to 10 kHz				
			for BC478 for BC479		1.5 1	4	dB dB
		$l_{C} = -20\mu A$ $R_{g} = 10 k\Omega$ B = 200 Hz	$V_{CE} = -5 V$ f = 1 kHz				
		$I_{C} = -200 \ \mu A$ $R_{g} = 2 \ k\Omega$	for <b>BC479</b> V <sub>CE</sub> = → 5 V f = 1 kHz		0.5	2.5	dB
		B = 200 Hz		1			
			for BC477		2	10	dB
			for BC478		1.2	6	dB
	I		for BC479		0.8	4	dB d

\* Pulsed : pulse duration = 300 µs, duty cycle = 1 %.

Collector-emitter Saturation Voltage.



Collector Cutoff Current.

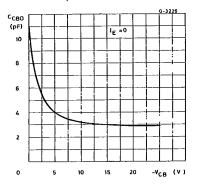




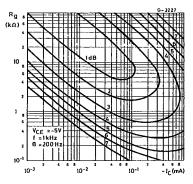
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## BC477-BC478-BC479 S G S-THOMSON 30E D ■ 7929297 0090916 T ■

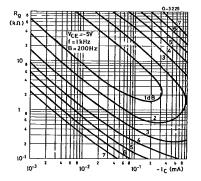
Collector-base Capacitance.



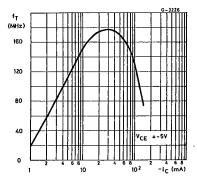
Noise Figure (for BC477 only).



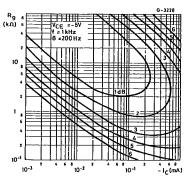
Noise Figure (for BC479 only).



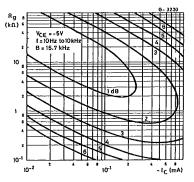
Transition Frequency.



Noise Figure (for BC478 only).



Noise Figure (for BC479 only).

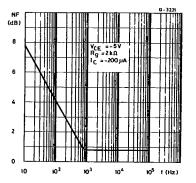




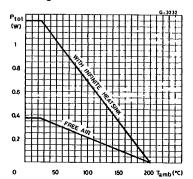
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Noise Figure vs. Frequency (for BC479 only).



Power Rating Chart.



BC477-BC478-BC479

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